



# **KSC2335F**

## High Speed, High Voltage Switching

Industrial Use

# **NPN Epitaxial Silicon Transistor**

1.Base 2.Collector 3.Emitter

TO-220F

**KSC2335F** 

Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

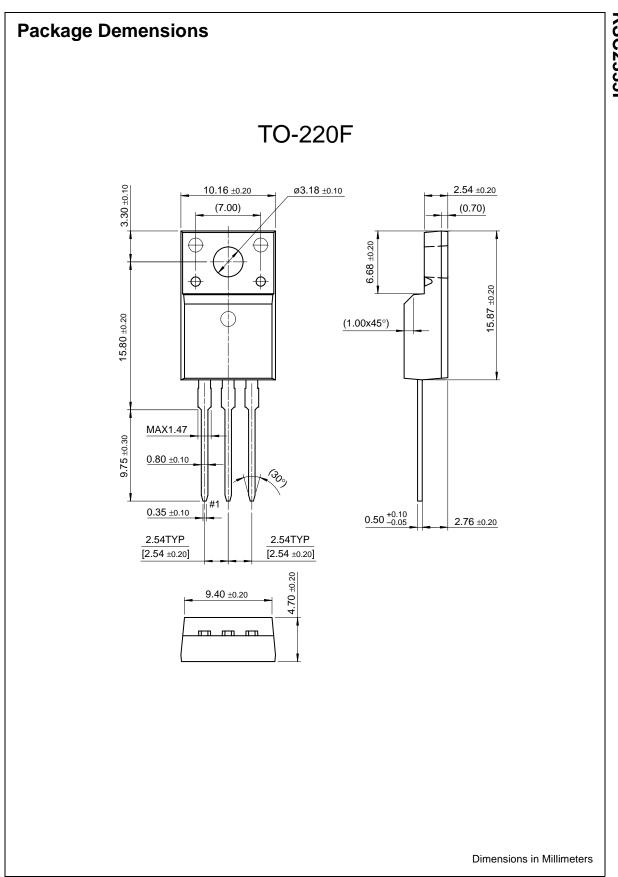
Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	7	V
I <sub>C</sub>	Collector Current (DC)	7	A
I <sub>CP</sub>	*Collector Current (Pulse)	15	A
I <sub>B</sub>	Base Current	3.5	A
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W
Т <sub>Ј</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage	I <sub>C</sub> =3A, I <sub>B1</sub> =0.6A, L = 1mH	400		V
V <sub>CEX</sub> (sus)1	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = <mark>3A,I<sub>B1</sub>=-I<sub>B2</sub>=0.6A</mark> V <sub>BE</sub> (off)=-5V, L = 180μH, Clamped	450		V
V <sub>CEX</sub> (sus)2	Collector-Emitter Sustaining Voltage	I <sub>C</sub> =6A, I <sub>B1</sub> =2A, I <sub>B2</sub> =-0.6A V <sub>BE</sub> (off)=-5V, L = 180μH, Clamped	400		V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CE}$ =400V, $I_{E}$ = 0		10	μΑ
ICER	Collector Cut-off Current	V <sub>CE</sub> =400V, R <sub>BE</sub> = 51Ω @ T <sub>C</sub> = 125°C		1	mA
I <sub>CEX1</sub>	Collector Cut-off Current	V <sub>CE</sub> =400V, V <sub>BE</sub> (off) = -1.5V		10	μA
I <sub>CEX2</sub>	Collector Cut-off Current	V <sub>CE</sub> =400V, V <sub>BE</sub> (off) = -1.5V @ T <sub>a</sub> =125°C	83	1	mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}=5V, I_{C}=0$	and W	10	μΑ
h <sub>FE1</sub> h <sub>FE2</sub> h <sub>FE3</sub>	* DC Current Gain	$V_{CE}=5V, I_{C} = 0.1A$ $V_{CE}=5V, I_{C} = 1A$ $V_{CE}=5V, I_{C}=3A$	20 20 10	80	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> =3A, I <sub>B</sub> =0.6A		1	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> =3A, I <sub>B</sub> =0.6A		1.2	V
t <sub>ON</sub>	Turn ON Time	V <sub>CC</sub> =150V, I <sub>C</sub> =3A		1	μs
t <sub>STG</sub>	Storage Time	$I_{B1}=-I_{B2}=0.6A$		2.5	μs
t <sub>E</sub>	Fall Time	$R_L=50\Omega$		1	μs

### hee Classification

TE							
Classification	R	0	Y				
PDE h <sub>FE1</sub>	20 ~ 40	30 ~ 60	40 ~ 80				



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